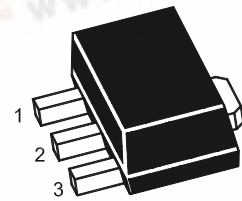


ST 2SB1424U

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PNP Silicon Epitaxial Planar Transistor



1.Base 2.Collector 3.Emitter
SOT-89 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	20	V
Collector Emitter Voltage	$-V_{CEO}$	20	V
Emitter Base Voltage	$-V_{EBO}$	6	V
Collector Current - DC	$-I_C$	3	A
Collector Current - Pulse ¹⁾	$-I_{CP}$	5	A
Total Power Dissipation	P_{tot}	0.5	W
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_S	- 55 to + 150	$^\circ\text{C}$

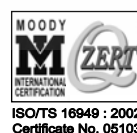
¹⁾ Single pulse, PW = 10 ms.

Characteristics at $T_a = 25^\circ\text{C}$

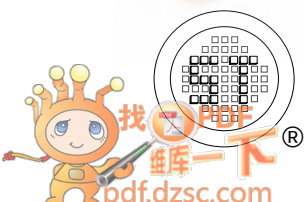
Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $-V_{CE} = 2\text{ V}$, $-I_C = 100\text{ mA}$	Current Gain Group Q R h_{FE} h_{FE}	120	-	270	-
		180	-	390	-
Collector Base Breakdown Voltage at $-I_C = 50\text{ }\mu\text{A}$	$-V_{(BR)CBO}$	20	-	-	V
Collector Emitter Breakdown Voltage at $-I_C = 1\text{ mA}$	$-V_{(BR)CEO}$	20	-	-	V
Emitter Base Breakdown Voltage at $-I_E = 50\text{ }\mu\text{A}$	$-V_{(BR)EBO}$	6	-	-	V
Collector Cutoff Current at $-V_{CB} = 20\text{ V}$	$-I_{CBO}$	-	-	0.1	μA
Emitter Cutoff Current at $-V_{EB} = 5\text{ V}$	$-I_{EBO}$	-	-	0.1	μA
Collector Emitter Saturation Voltage at $-I_C = 2\text{ A}$, $-I_B = 100\text{ mA}$	$-V_{CE(sat)}$	-	-	0.5	V
Transition Frequency at $-V_{CE} = 2\text{ V}$, $-I_E = 0.5\text{ A}$, $f = 100\text{ MHz}$	f_T	-	240	-	MHz
Output Capacitance at $-V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$	C_{ob}	-	35	-	pF

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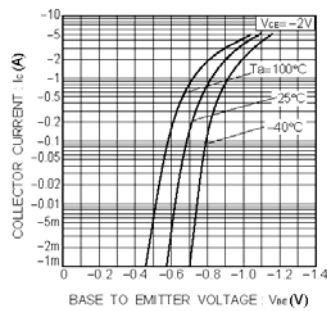


Fig.1 Grounded emitter propagation characteristics

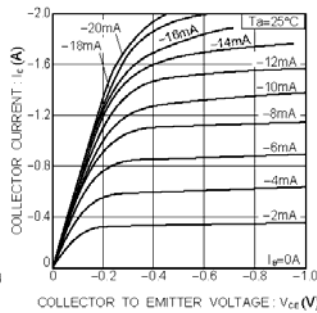


Fig.2 Grounded emitter output characteristics (I)

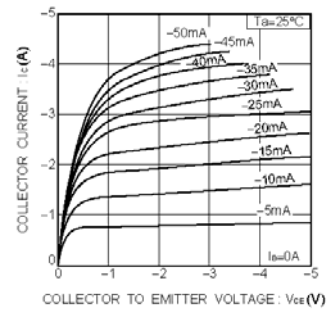


Fig.3 Grounded emitter output characteristics (II)

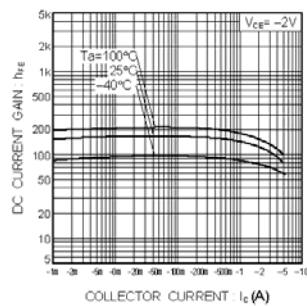


Fig.4 DC current gain vs. collector current

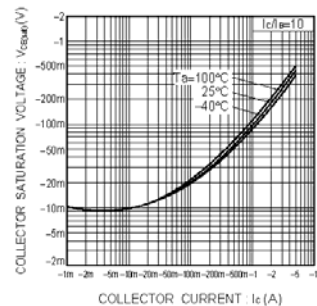


Fig.5 Collector-emitter saturation voltage vs. collector current (I)

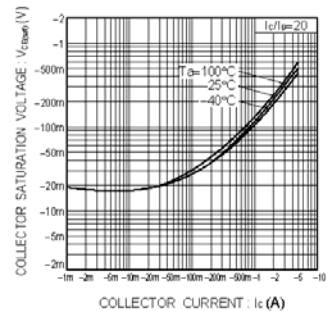


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

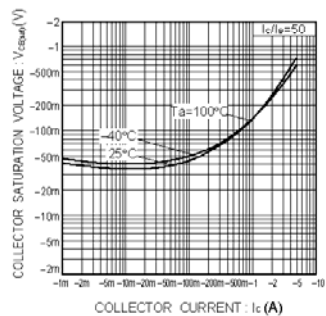


Fig.7 Collector-emitter saturation voltage vs. collector current (III)

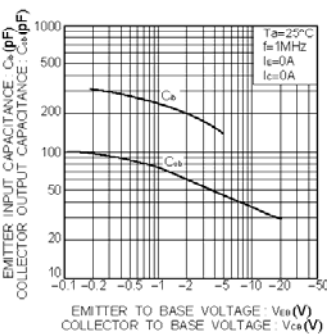


Fig.8 Gain bandwidth product vs. emitter current
 Collector output capacitance vs. collector-base voltage

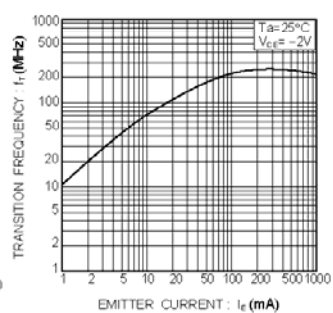
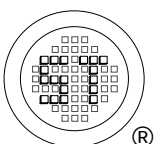
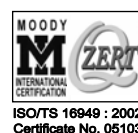


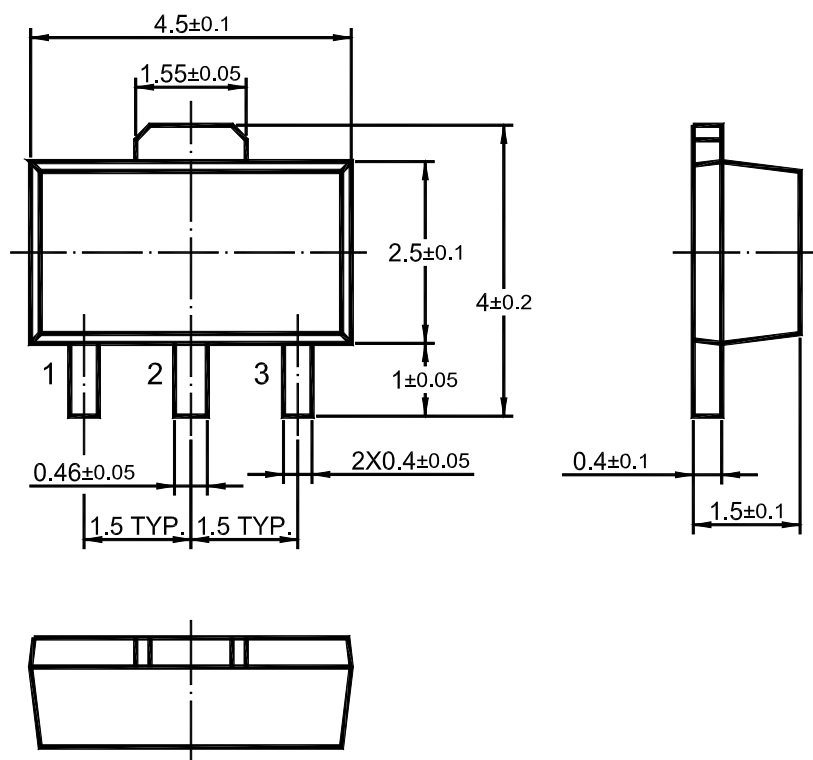
Fig.9 Emitter input capacitance vs. emitter base voltage



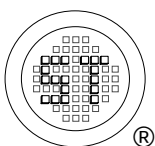
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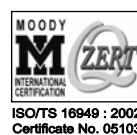
SOT-89 PACKAGE OUTLINE



Dimensions in mm



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